Photo Semiconductor Device - Page 1 of 1



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I	Metal
	Dverall Length:
	Between 0.140 inches and 0.150 inches
	Nounting Facility Quantity:
	1
,	Joint Electronic Device Engineering Council/jedec/case Outline Designation:
	Го-46
I	Nounting Method:
I	Jnthreaded hole
;	Semiconductor Material:
(Gallium arsenide
,	Voltage Rating In Volts Per Characteristic:
	2.0 forward voltage, dc and 2.0 reverse voltage, instantaneous
(Current Rating Per Characteristic:
,	100.00 milliamperes source cutoff current preset
l	Maximum Operating Tempurature Per Measurement Point:
,	125.0 degrees celsius ambient air
•	Ferminal Type And Quantity:
	2 uninsulated wire lead
;	Shelf Life:
l	N/a
l	Jnit Of Measure:
•	-
l	Demilitarization:
ļ	No
	Filg:
,	A110a0